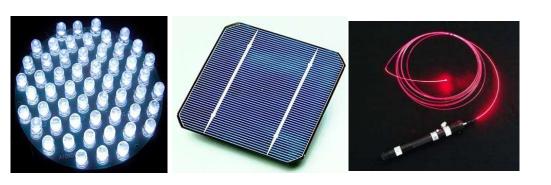
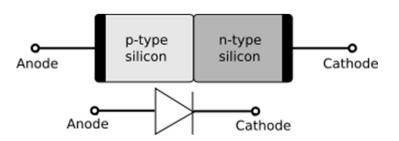
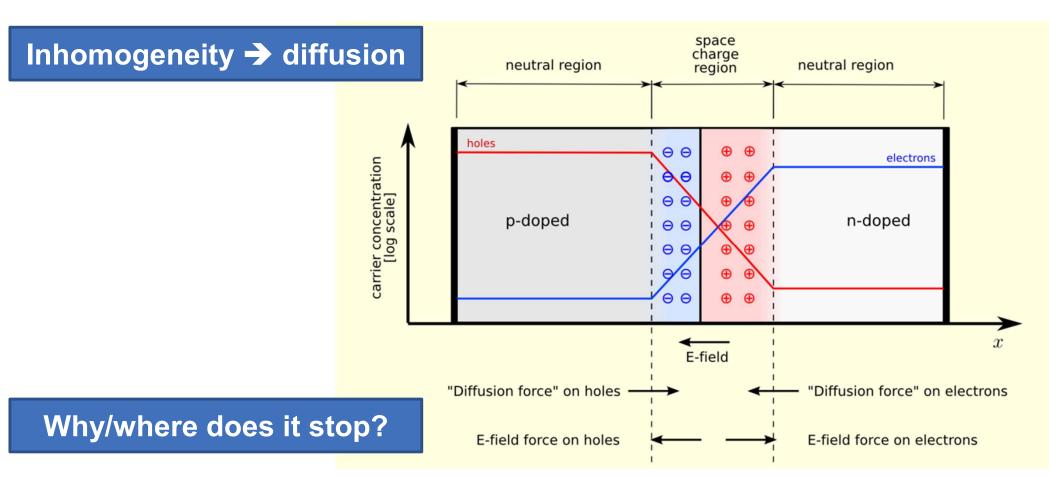
Idealized p-n junction diode



Ideal approximation: 1-D, abrupt





Equilibrium barrier height...

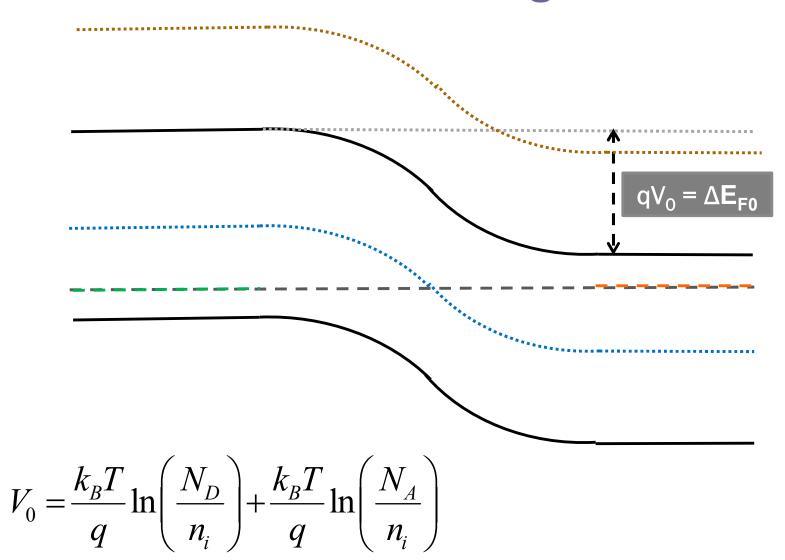
Vacuum

$$\mathsf{E}_\mathsf{c}$$

$$E_{Fp} = E_i - \ln\left(\frac{p_{p0}}{n_i}\right) = E_i - \frac{k_B T}{q} \ln\left(\frac{N_A}{n_i}\right) \quad E_{Fn} = E_i + \ln\left(\frac{n_{n0}}{n_i}\right) = E_i + \frac{k_B T}{q} \ln\left(\frac{N_D}{n_i}\right)$$

$$\Delta E_{F0} = E_{Fn} - E_{Fp} = \frac{k_B T}{q} \ln \left(\frac{N_D}{n_i} \right) + \frac{k_B T}{q} \ln \left(\frac{N_A}{n_i} \right)$$

...from band diagram



Contact potential / built-in voltage

$$V_0 = \frac{k_B T}{q} \ln \left(\frac{N_A N_D}{n_i^2} \right)$$

Hetero-junction?

Equilibrium with potentials/band-bending

Equilibrium, homogeneous

$$n_0 = n_i \exp\left(\frac{E_F - E_{i0}}{k_B T}\right) \qquad p_0 = n_i \exp\left(\frac{E_{i0} - E_F}{k_B T}\right)$$

Equilibrium, inhomogeneous

$$n = n_i \exp\left(\frac{E_F - E_{i0} + eV}{k_B T}\right) = n_0 \exp\left(\frac{+eV}{k_B T}\right) \qquad E_i = E_{i0} - eV$$

$$p = n_i \exp\left(\frac{E_{i0} - E_F - eV}{k_B T}\right) = p_0 \exp\left(\frac{-eV}{k_B T}\right)$$

Drift = Diffusion?

Contact potential?

Finis

Artwork Sources:

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- 2. TheNoise, commons.wikimedia.org
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- 4. www.instructables.com
- 5. <u>en.wikipedia.org</u>
- 6. <u>www.thefoa.org</u>